Analog Power AM6922NH

Dual N-Channel Logical Level MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)}$ (OHM)	$I_{D}(A)$		
	$0.018 @ V_{GS} = 4.5 V$	6.7		
20	$0.024 @ V_{GS} = 2.5V$	5.8		
	$0.034 @ V_{GS} = 1.8V$	4.9		

- $\hbox{ Low $r_{DS(on)}$ provides higher efficiency and} \\ \hbox{ extends battery life}$
- Low thermal impedance copper leadframe TSSOP-8 saves board space
- Fast switching speed
- High performance trench technology

_	TSSOP-8 Top View	_	D	D
S1 \square	1 8 2 7 3 6 4 5	□□ D □□ S2 □□ S2 □□ G2	G ₁ S ₁ N-Channel MOSFET	G_2 S_2 N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Paramete r		Symbol	Maximum	Units	
Drain-Source Voltage			20	V	
Gate-Source Voltage	V_{GS}	±8	V		
Continuous Drain Current ^a $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$			6.7	A	
		1D	5.5		
Pulsed Drain Current ^b	I_{DM}	±30			
Continuous Source Current (Diode Conduction) ^a		I_S	1.5	A	
Power Dissipation ^a $ T_{A}=25^{\circ}C $ $ T_{A}=70^{\circ}C $		D	1.2	W	
		r _D	0.8	**	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Тур	Max		
M · I	t <= 10 sec	D	72	83	°C/W
Maximum Junction-to-Ambient ^a	Steady State	R_{thJA}	100	120	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	VGS = VDS, $ID = 250 uA$	0.4			V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			±10	μΑ	
Zara Gata Valtaga Drain Current	I_{DSS}	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ	
Zero Gate Voltage Drain Current	¹ DSS	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			10	μΑ	
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			A	
		$V_{GS} = 4.5 \text{ V}, \text{ ID} = 1 \text{ A}$			0.018		
Drain-Source On-Resistance ^A	$r_{DS(on)}$	VGS = 2.5 V, ID = 1 A			0.024	Ω	
		$V_{GS} = 1.8 \text{ V}, \text{ ID} = 1 \text{ A}$			0.034		
Forward Tranconductance ^A	g_{fs}	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ A}$		25		S	
Diode Forward Voltage ^A	V_{SD}	$I_S = 1 A$, $V_{GS} = 0 V$		0.7		V	
Dynamic ^b	-		-		•	=	
Total Gate Charge	Q_{g}			6.2			
Gate-Source Charge	Q_{gs}	V_{DS} =10V, V_{GS} =4.5V, I_{D} =1A		1.0		nC	
Gate-Drain Charge	Q_{gd}			1.9			
Turn-On Delay Time	$t_{d(on)}$			12		nS	
Rise Time	t _r	$V_{DD}=10V$, $VGS=4.5V$, $ID=1A$,		15			
Turn-Off Delay Time	$t_{d(off)}$	$R_{\text{GEN}} = 10\Omega$		56			
Fall-Time	t_{f}			17			

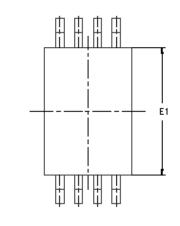
Notes

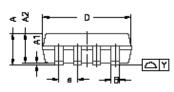
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

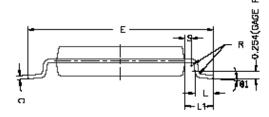
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Package Information

TSSOP-8: 8LEAD







DIM.	MILLIMETERS				
	MIN.	NDM.	MAX.		
A	1.05	1.10	1.20		
A(1)	0.05	0.10	0.15		
A(2)	0.99	1.02	1.05		
В	D.19	0.25	0.30		
C		0.127			
D	2.90	3.0D	3.10		
Ε	6.20	6.40	6,60		
E1	4.30	4.40	4.50		
В	0.659SC				
L	0.45	0.60	0.75		
L1	0.90	1.00	1.10		
Y			0.10		
8 1	O.	4	Ē.		
R	0.09		-		
S	0.20				